

## Micro Infrared Receiver Module

1-05-08-30

#### Module No.: PIC-5811ASMB

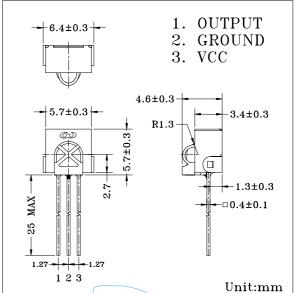
#### 1. Features:

- ➤ Microminiature size
- Built-in exclusive IC
- **CMOS** Design
- Wide half angle & long reception distance
- Good noise-proof capability
- High immunity against ambient light
- High protection ability to EMI
- Back Metal Cover
- > Side view
- ➤ Mesh
- Wide voltage operating:  $2.7V \sim 5.5V$

## 2. Applications

- AV instruments (Audio, TV, VCR, CD player)
- Home appliances (Air-conditioner, Fan, Light.)
- Remote control for wireless devices

#### **Dimensions**



## 3. Absolute Maximum Ratings.

3. Absolute Maximum I	Katings	(T)	$a=25^{\circ}C$
Parameter	Symbol	Ratings	Unit
Supply Voltage	Vcc	6.0	V
Operating Temperature	Topr	-10 ~ +60	°C
Storage Temperature	Tstg	-20 ~ +75	$^{\circ}\mathrm{C}$
Soldering Temperature *1	Tsol	240	°C

<sup>\*1</sup> At the position of 2mm from the bottom of the package within 5 seconds.

#### 4. Electro-optical Characteristics

(7	Га—	25	°C	١
	1 a-	4.)	•	,

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Supply voltage	Vcc		2.7		5.5	V
Current Consumption	Icc	Input Signal = 0		1.0	1.2	mA
Reception Distance	d	200±5Lux,Vcc=3.0V	10	16		m
Half Angle (Horizontal)	$\Delta\theta h$			±45		deg
Half Angle (Vertical)	$\Delta \theta v$			+45/-40		deg
B.P.F. Center Frequency	Fo			37.9		kHz
Peak Wavelength	λр			940		nm
Signal Output	So		Active Low			
High Level Output Voltage	Voh		Vcc-0.3			V
Low Level Output Voltage	Vol				0.25	V
High Level Pulse Width	Twh	Burst Wave = 600µs	500	600	700	μs
Low Level Pulse Width	Twl	buist wave = 600µs	500	600	700	μs

### 5. Reliability Test Items

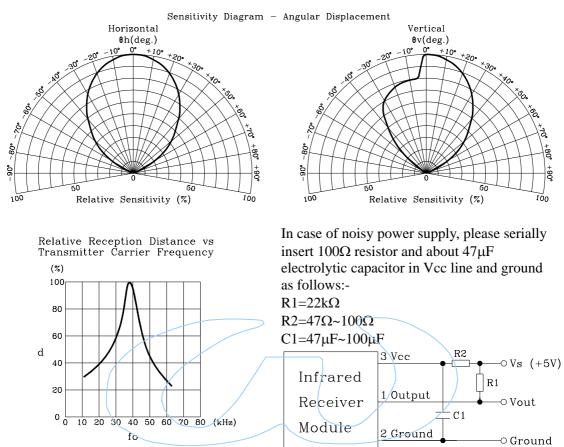
(Ta=	=25°	$C \cap C$
( 1a–	-23	(U

e. Iteliaeliity Test Iteliis		(14 25 0)
Test Items	Test Conditions	Ratings
High Temperature Storage	Ta=60°C, Vcc=3.0V	t=240hr.
Low Temperature Storage	Ta=-10°C, Vcc=3.0V	t=240hr.
High Temperature High Humid Storage	Ta=40°C, 90%RH, Vcc=3.0V	t=240hr.
Temperature Cycling	$-20^{\circ}$ C (30min) ~ $+70^{\circ}$ C (30min)	20 cycles
Soldering Heat	240±5°C	5 sec.

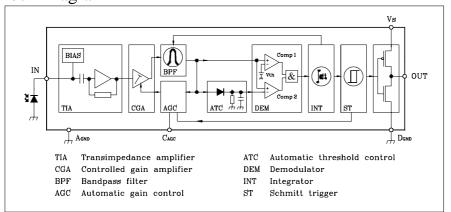
# WAITRONY 慧創就

## Micro Infrared Receiver Module

### Module No.: PIC-5811ASMB



## **Block Diagram**



Caution: This device is CMOS design. The signal output port of this device should drive the input port of the next stage device UNILATERALLY. Directly connecting the output port of this device with that of other device is not allowed and will cause the device to be damaged.

#### **Standard Inspection**

Among electrical characteristics, total quantity will be inspected as below:-

- Distance between emitter and detector
- Current consumption
- ⊙ H level output voltage
- L level output voltage



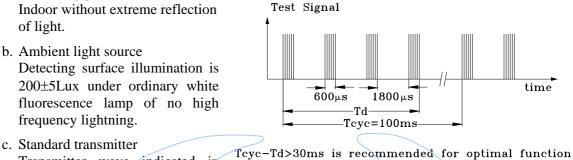
## Micro Infrared Receiver Module

## Module No.: PIC-5811ASMB

## **Testing Method**

Distance between emitter detector specifies maximum distance that output waveform satisfies the standard (FIG-3) under the conditions below against the standard transmitter.

- a. Measuring place Indoor without extreme reflection of light.
- b. Ambient light source frequency lightning.



Standard Transmitter

Transmitter wave indicated in FIG-2 of standard transmitter is arranged to satisfy Vo≥50mVp-p under the measuring circuit specified in FIG-3

Output Signal Vo Voh Vol time FIG-2

FIG-1

Sensing Distance: d

 $\bigcirc$  Vcc

 $\bigcirc$  OUT

 $\odot$  GND

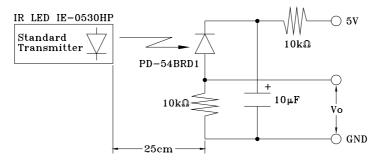


FIG-3Power Output Measurement Circuit

#### Precautions for Use

- a. Store and use where there is no force causing transformation or change in quality.
- b. Store and use where there is no corrosive gas or sea (salt) breeze.
- c. Store and use where there is no extreme humidity.
- d. Solder the lead pin within the condition of ratings. After soldering, do not add exterior force.
- e. Do not wash this device. Wipe the stains of diode side with a soft cloth. You can use the solvent, ethyl alcohol, or methyl alcohol only.
- f. To prevent static electricity damage to the pre-amp, make sure that the human body, the soldering iron are connected to ground before using.